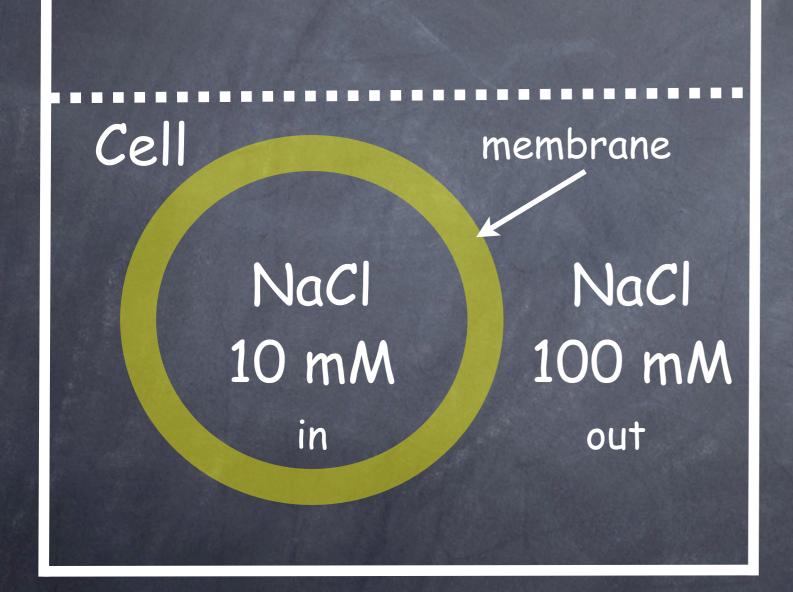
Passive electrical properties of the neuron

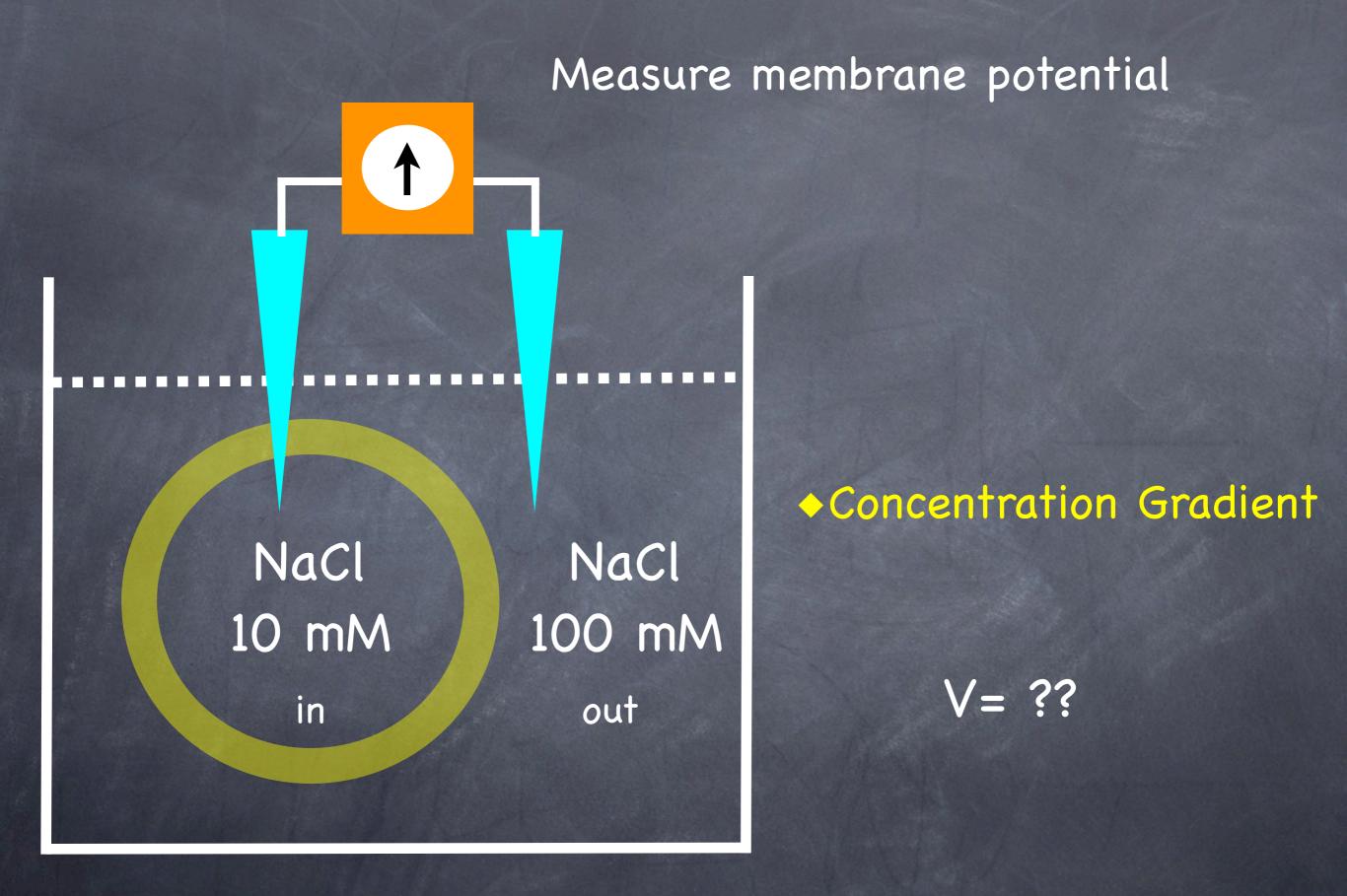
Ricardo C. Araneda rca23@columbia.edu/4-4539 Fall 2004

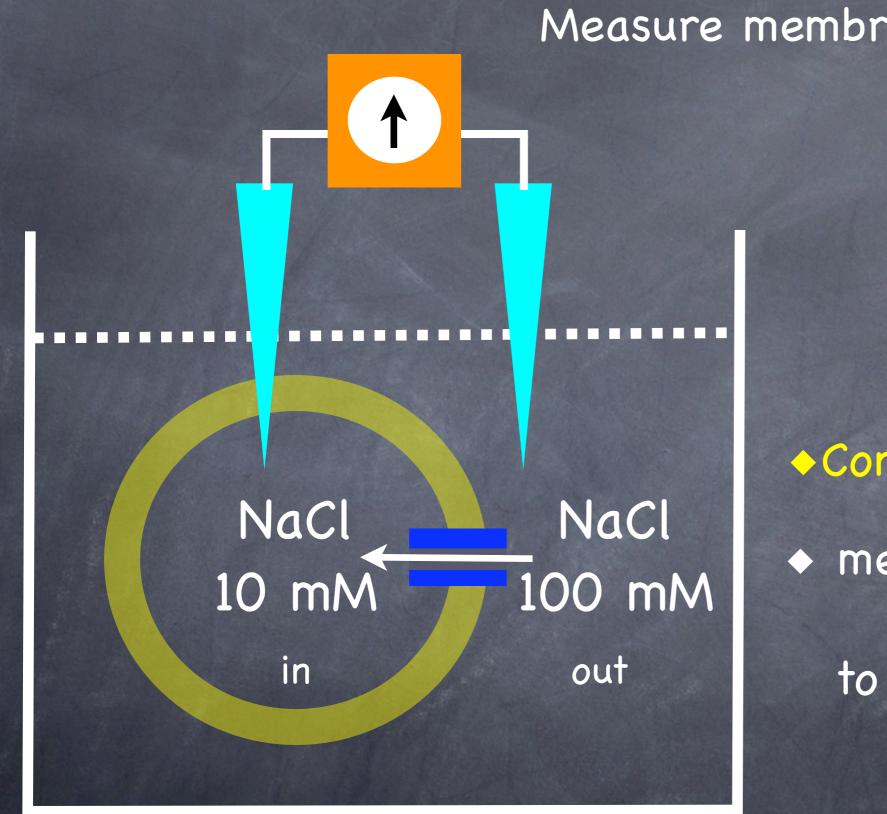
The following books were used for the lecture: "From neuron to brain" Nicholls et al., 3rd Ed. "Ion channels of excitable membranes" B. Hille, 3rd Ed. "Fundamental neuroscience" Zigmond et al. "Principles of neuroscience" Kandel et al., 4th Ed.

Review of basic concepts Experiment 1



Concentration Gradient





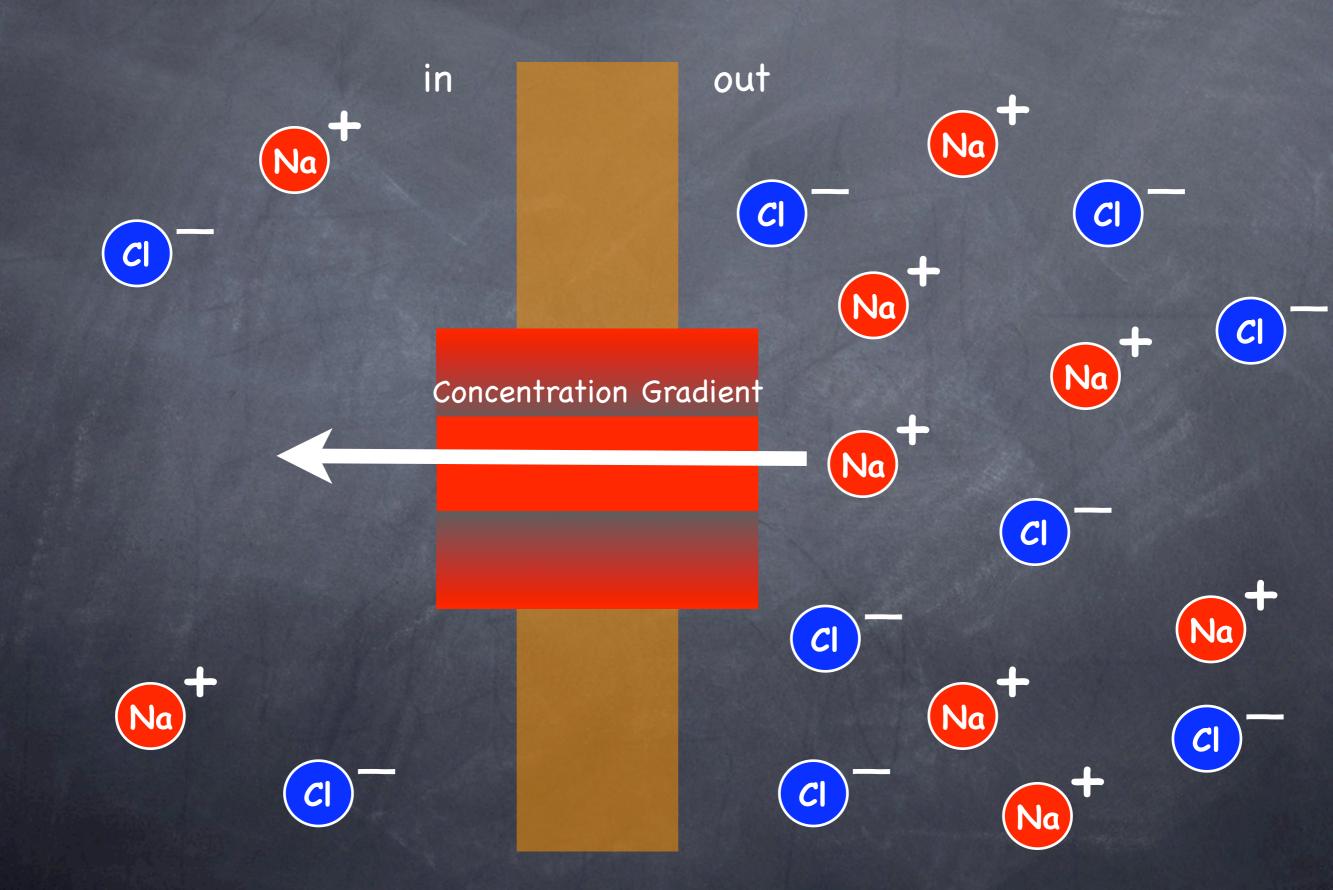
Measure membrane potential

Concentration Gradient

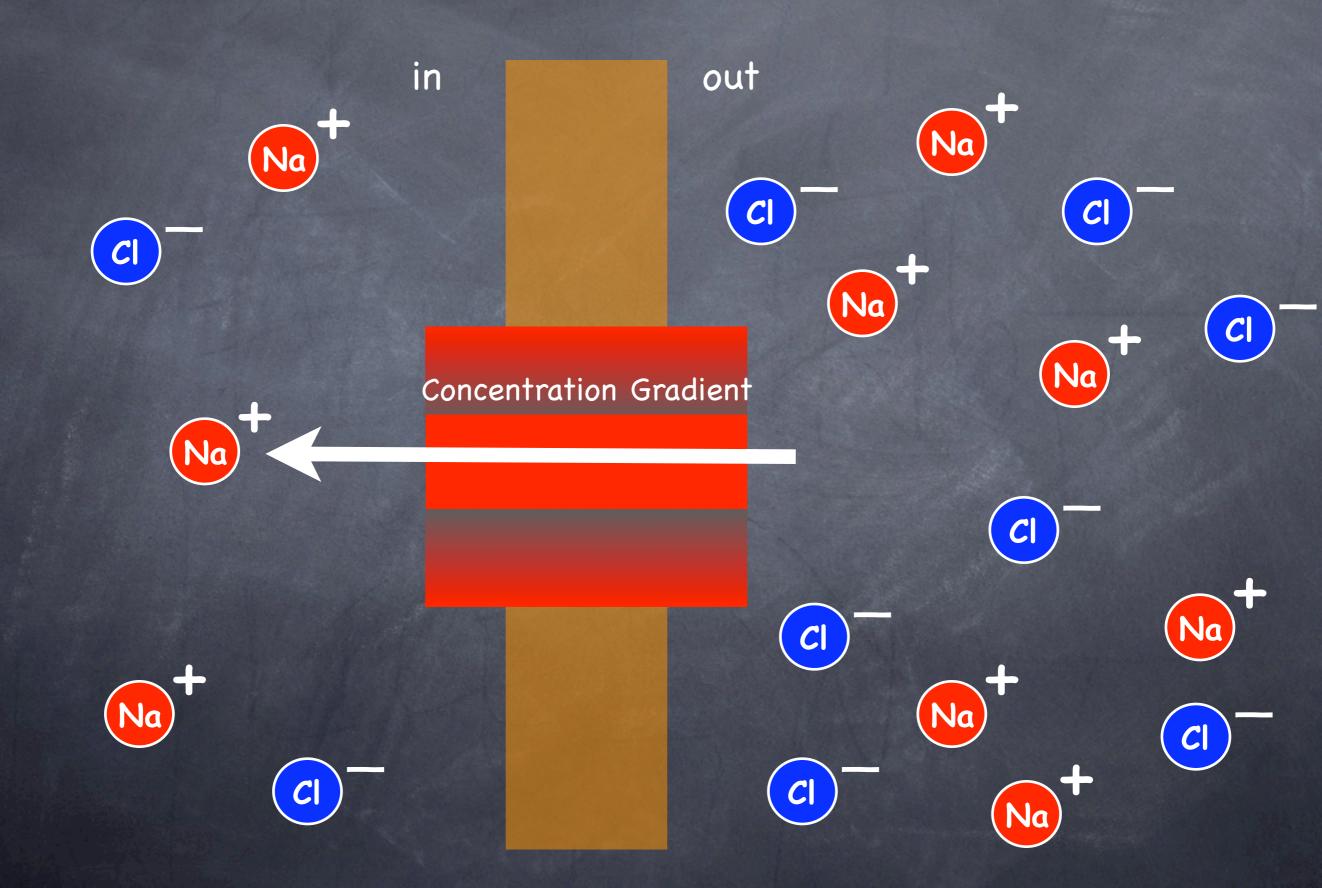
 membrane is equally permeable to both Na and Cl

V= ??

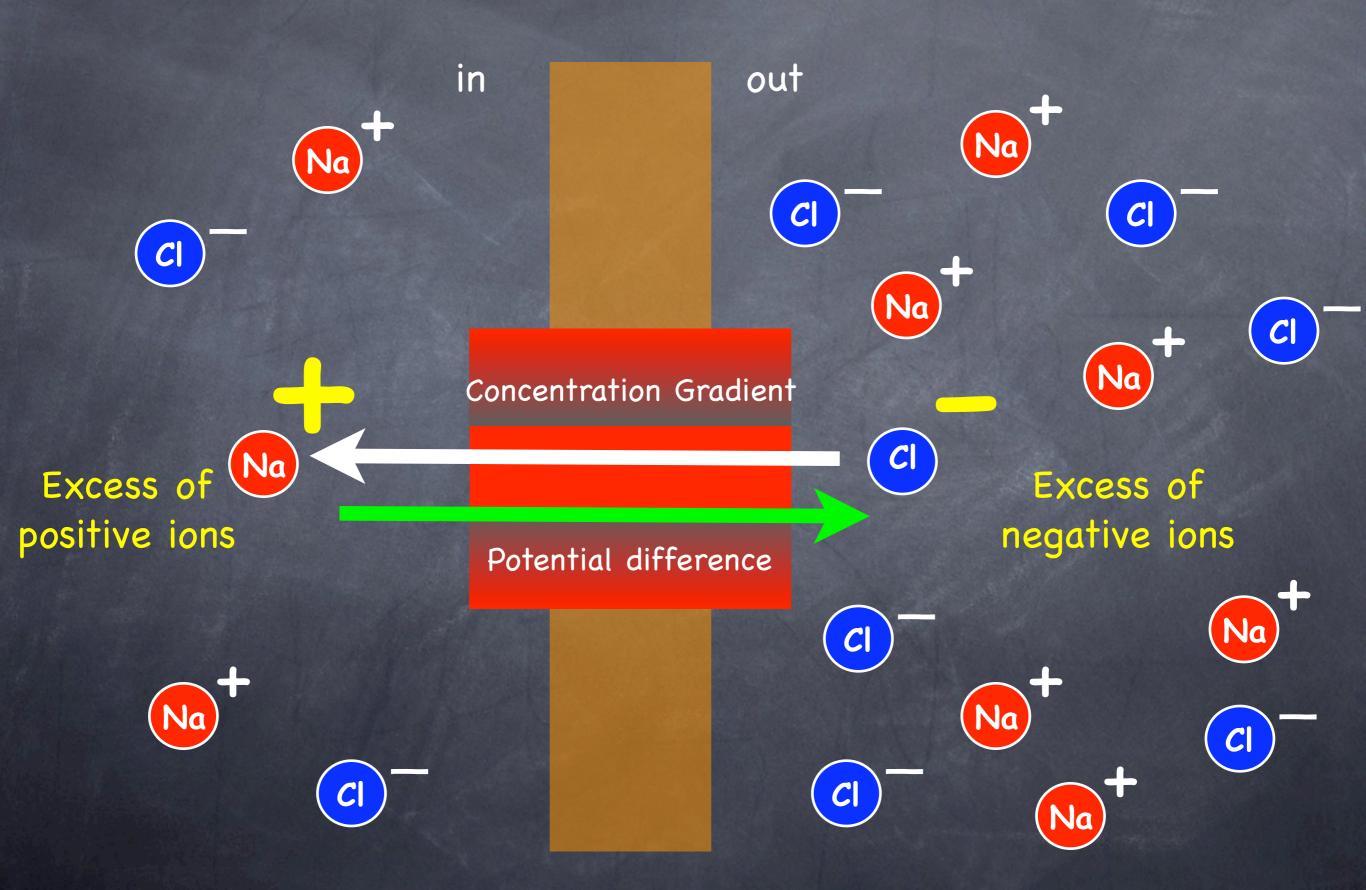
Membrane is selectively permeable to Sodium



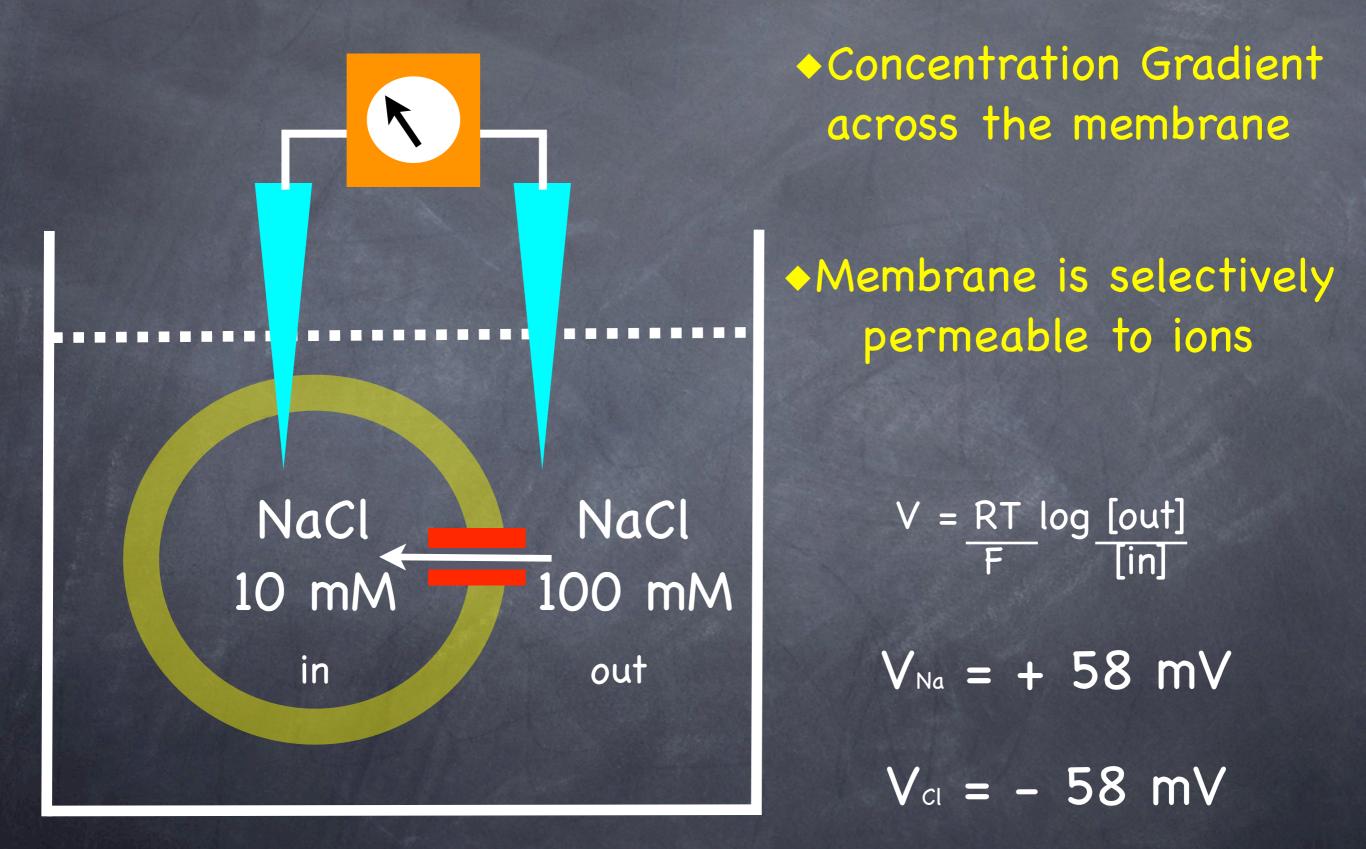
Membrane is selectively permeable to Sodium



Membrane is selectively permeable to Sodium



Membrane potential

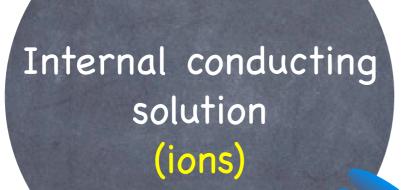


Membranes as capacitors

Internal conducting solution (ions) External conducting solution (ions)

Thin insulating layer (membrane, 4nm)

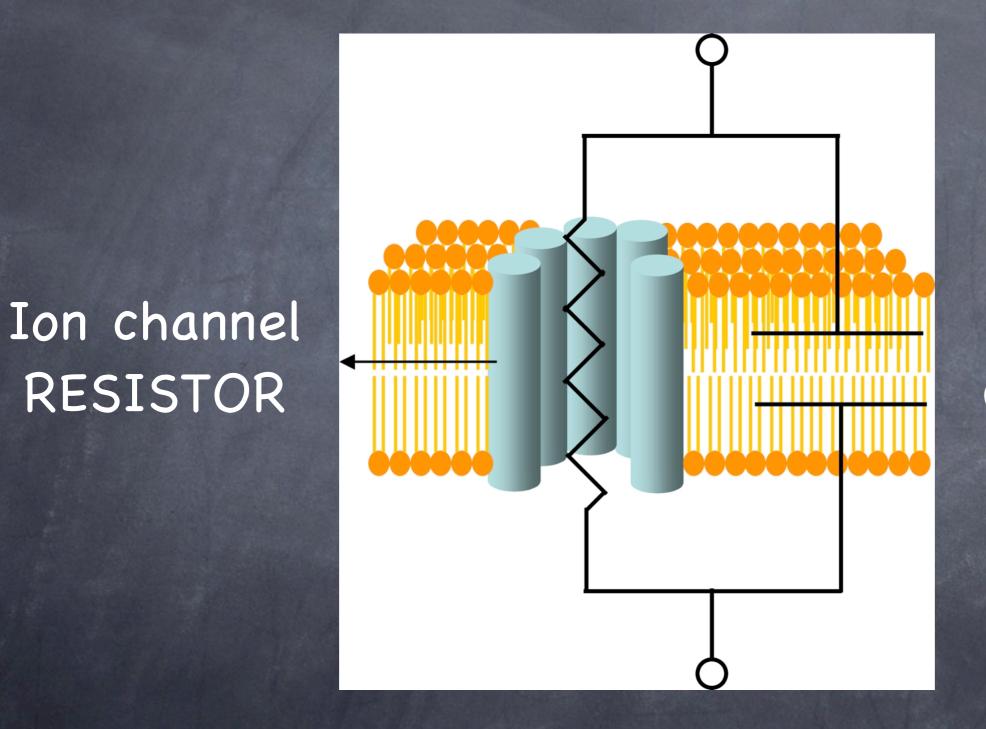
Membranes as Resistors



External conducting solution (ions)

Ion channels Voltage-gated, NT- gated etc.

Electrical model of the cell membrane



RESISTOR

Membrane CAPACITOR

Capacitor

+

+

+

 \bigcirc

+

A= Area



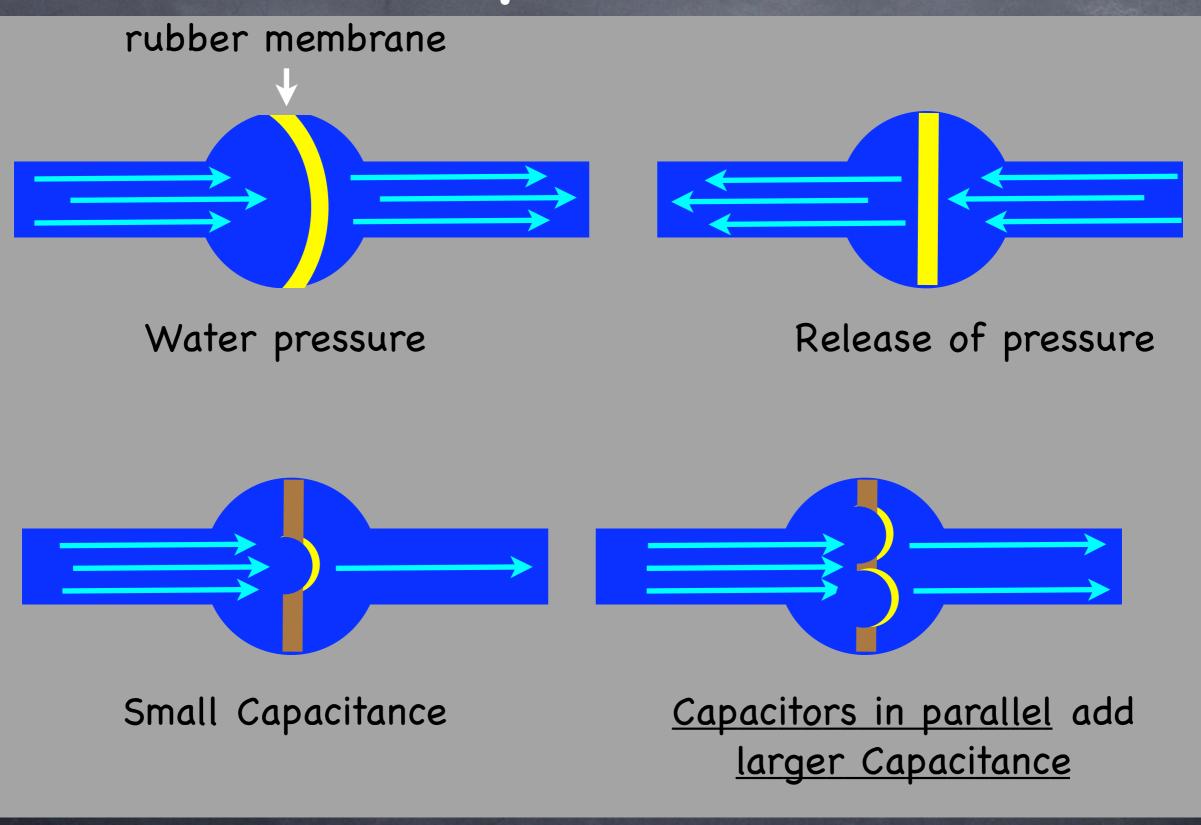
d = distance of plate
separation

Capacitance

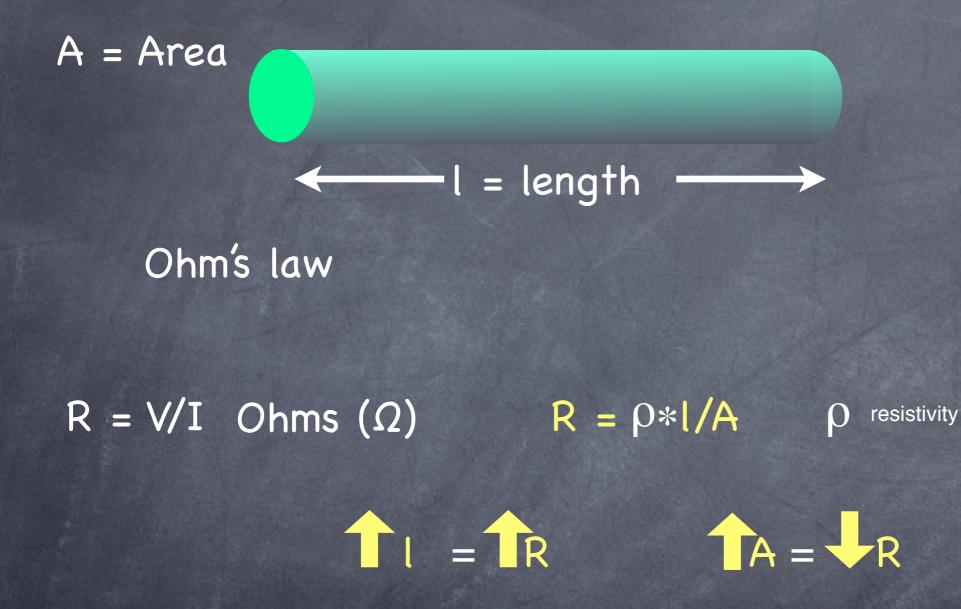
C = Q/V Coulomb/Volt or Farads (F)

 $C = \mathcal{E}_{o} * A/d$ \mathcal{E}_{o} electrostatic $\mathbf{1}_{A} = \mathbf{1}_{C}$ $\mathbf{1}_{d} = \mathbf{1}_{C}$

Capacitor

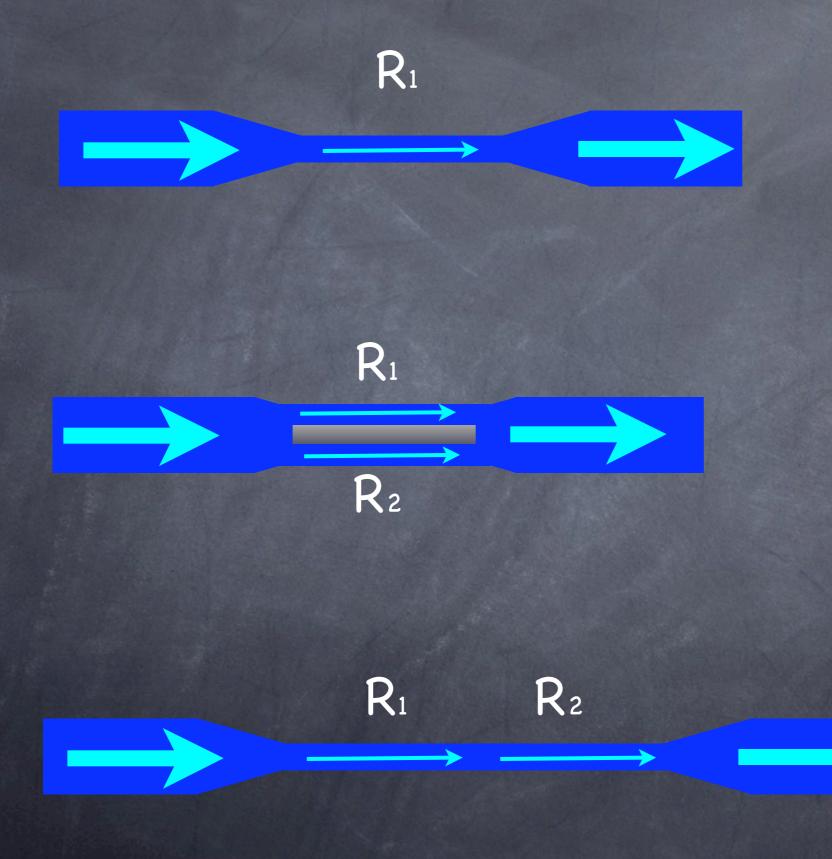


Resistance



For the same current, a larger R produces larger V

Resistors



For ion channels is better to think in terms of conductance

 $R_1 = 1/g_1$

As the # of Rs in parallel increases RT decreases!

 $1/R_{T} = 1/R_{1} + 1/R_{2}$

More (open) channels in the membrane more conductance

 $g_{T} = g_{1} + g_{2}$

$\mathbf{R}_{\mathrm{T}} = \mathbf{R}_{1} + \mathbf{R}_{2}$

Long, thin parts of a neuron have large resistance!

Some useful equations

Current

Ohm's law

Capacitance

Voltage across capacitor

Changing the voltage in a capacitor

We change the charge by passing current

The change in V depends on the duration of Ic

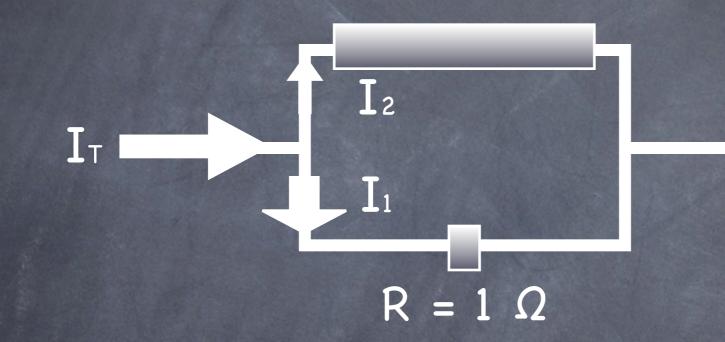
I = Coulombs/second Amperes (A) V = IRC = Q/V Coulombs/Volts (F) V = Q/C $\Delta V = \Delta Q/C$ Ic = $\Delta Q / \Delta t$

 $\Delta V = Ic * \Delta t / C$

Also remember...

Current likes to flow through the path with less resistance

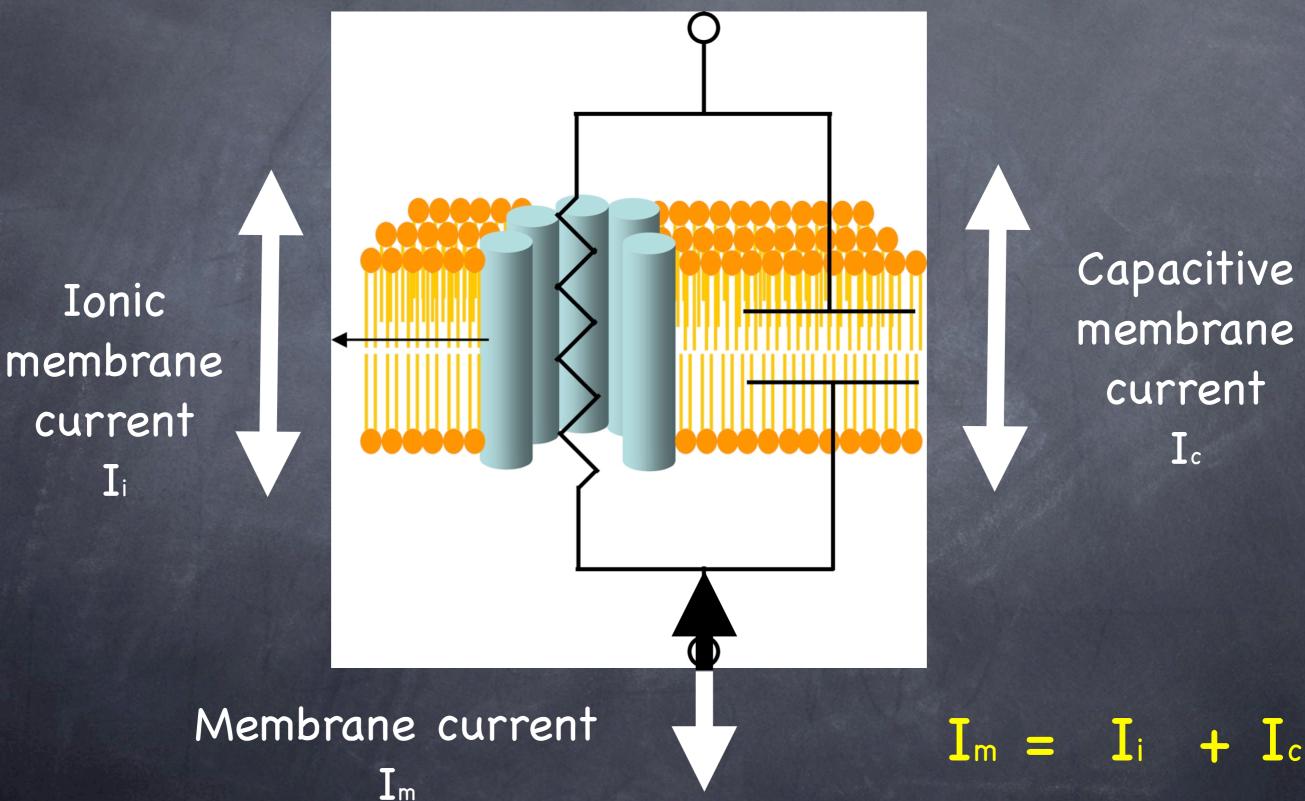
$R = 100 \Omega$



And

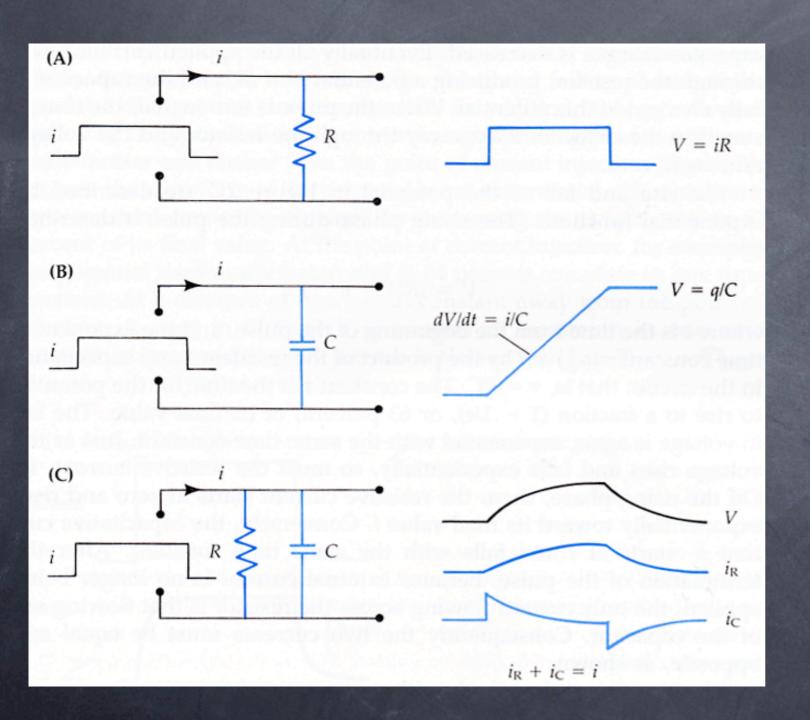
$\mathbf{I}_{\mathrm{T}} = \mathbf{I}_{1} + \mathbf{I}_{2}$

Electrical model of the cell membrane



Capacitive membrane current Ic

Effects of passing current on circuits containing R and C

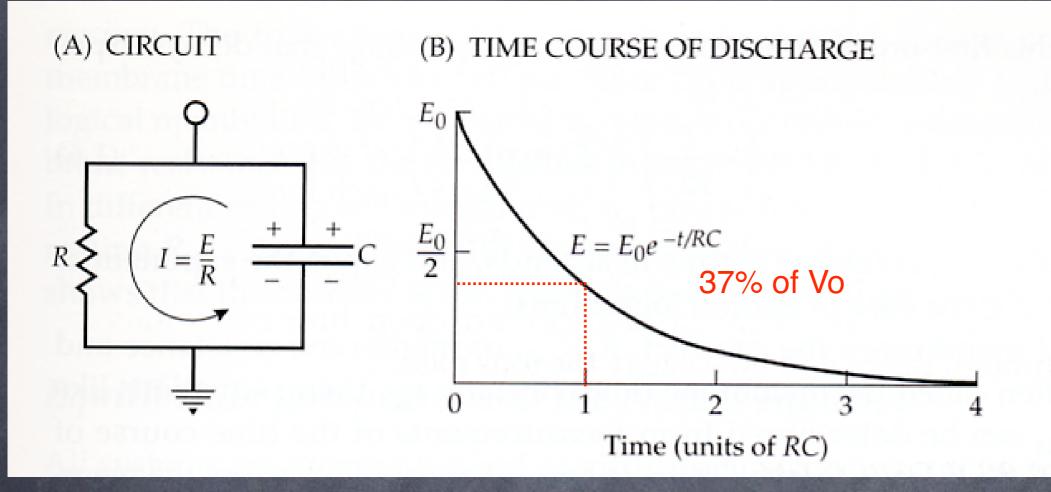


V changes <u>instantaneously</u> with I

V changes linearly <u>in time</u> with I

V changes <u>exponentially</u> with a time constant = RC

RC circuits



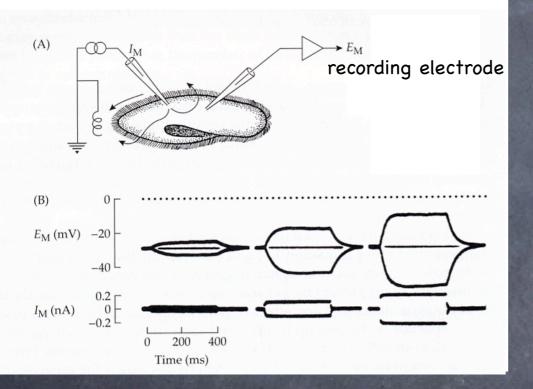
(E and V are the same)

For a rising exponential $V = V_0 * (1 - e^{-t/RC})$

Experiment 2

Passing current and recording the membrane potential from a paramecium

current-passing electrode

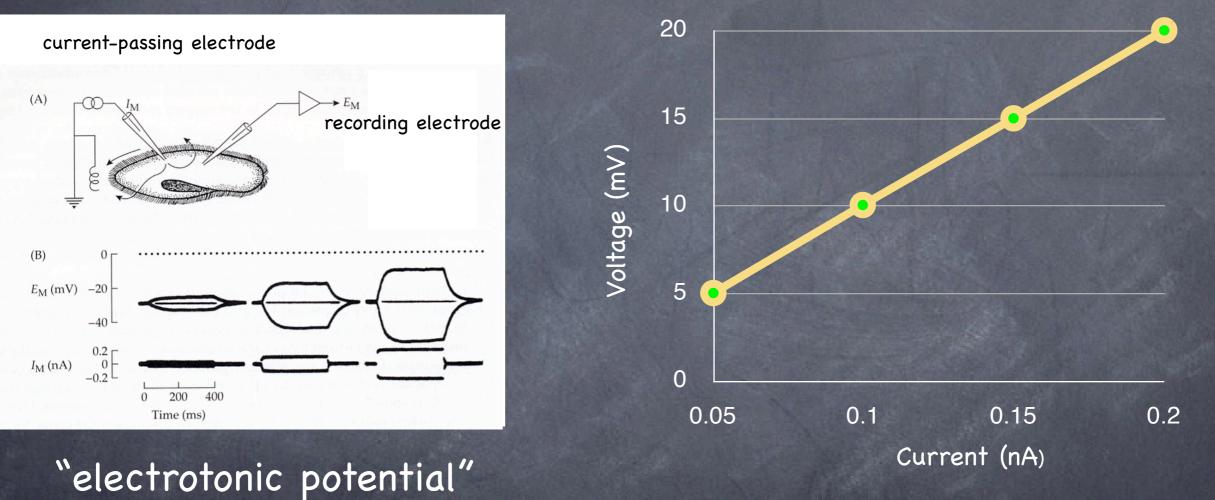


"electrotonic potential"

Negative current makes the membrane potential more negative hyperpolarization

Positive current makes the membrane potential more positive depolarization

Linear relationship between current and voltage

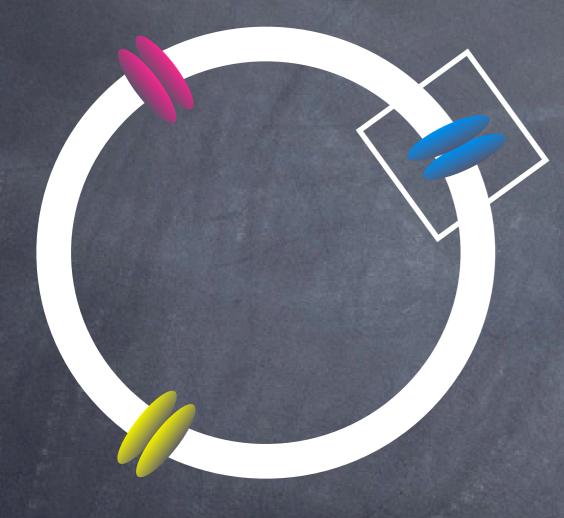


 $V = I * R_{in}$

Input Resistance $R_{in} = 100 M\Omega$

Specific membrane resistance

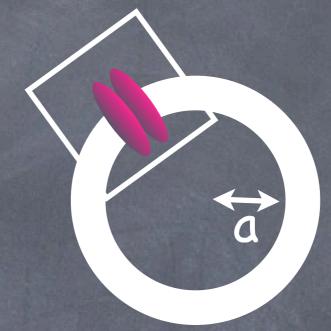
cross section of a cell



To compare cell with different sizes The specific membrane resistance (resistance per area) $R_{M} = \Omega * cm^{2}$ depends on the # of channels per cm² More channels make RM smaller For a spherical cell $R_{in} = R_M / 4\pi a^2$ a = radius

Rin determines how much the cell depolarizes in response to a steady current

Example same $R_M = 2000 \Omega * cm^2$



Cell diameter is 5 μ m

your numbers here ...

Cell diameter is 50 µm $a = 25 µm = 25*10^{4} cm$ $R_{in} = R_M/4\pi a^2$ $R_{in} = 2000 \Omega*cm^2/4\pi(25*10^{-4}cm)^2$ $R_{in} = 25 M\Omega$

0

Rin = 637 MΩ Rin is larger in a smaller cell

Specific membrane capacitance of biological membranes

 $C_{M} = 1 \ \mu F/cm^{2}$ For a cell at -80 mV how many ions is this? $C_{M} = Q/V$ $Q = 10^{6}C/V * 0.08 V$ $Q = 8 * 10^{-8} C/cm^{2}$ Faraday constant ≈ 10 Coulombs/mole Avogadro's number = 6.02×10^{23} mole⁻¹

Then this is 4.8*10 ions/cm² Is this a lot???

Let's assume the cell is 50 μ m in diameter



a = 25 μ m = 25*10⁴ cm surface of sphere A = 4 π a² A = 7.85*10⁻⁵ cm²

The volume of this cell is 6.55*10 cm Then this number of ions is $\sim 10^{-6}$ M If KCl inside is 120 mM this means that only ~1/120,000 ions is in excess!

Large cell large capacitance

Small cell small capacitance

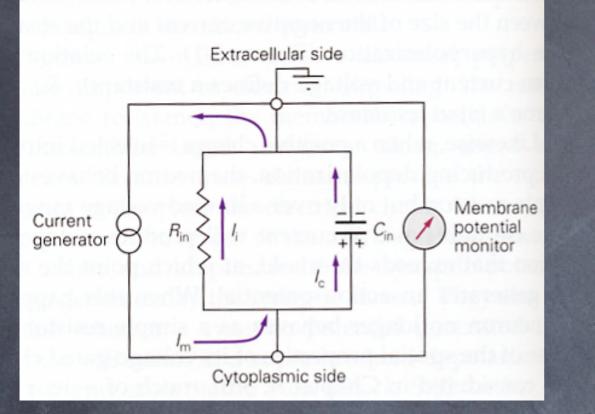
"Cm" is the same (same membrane)

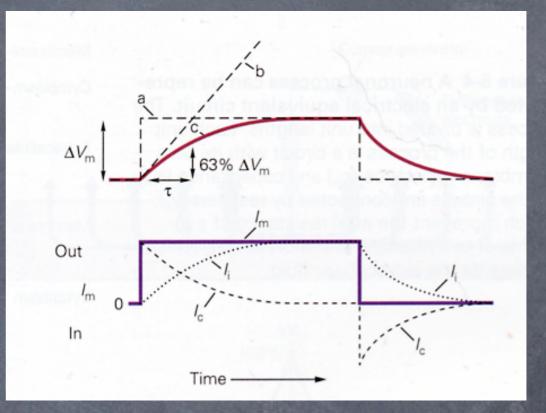
For a spherical cell, the input capacitance

 $C_{in} = C_M * 4\pi a^2$ a = radius

More charge (current) is required to change the voltage across a large cell

In summary



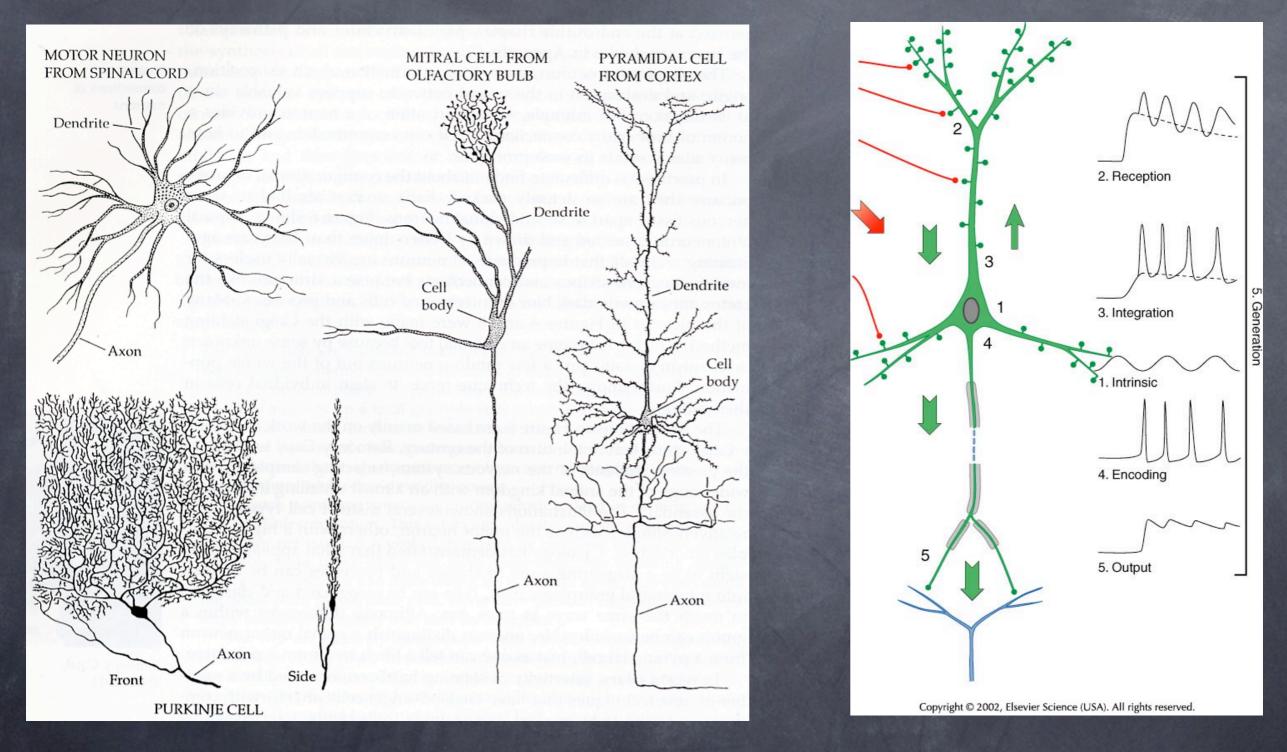


 $R_{in} = R_M / 4\pi a^2$ $C_{in} = C_M * 4\pi a^2$

 $T = R_{in} * C_M$

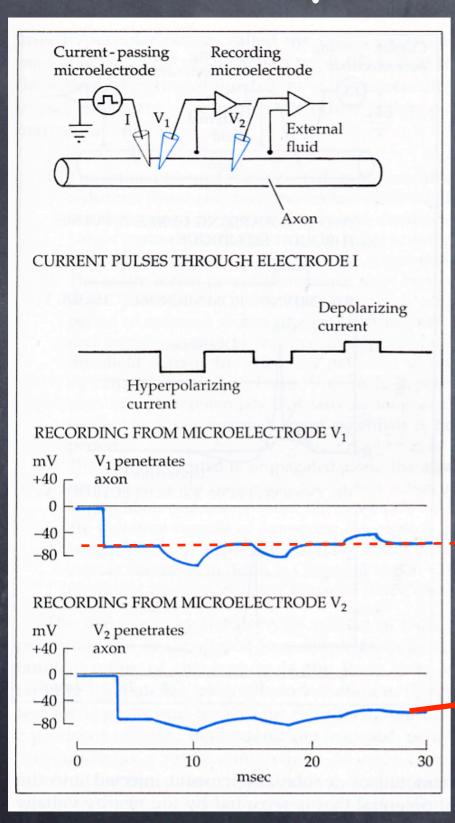
The product of input Capacitance and Resistance (T) determines the time it takes change the potential Notice that (T) is <u>not affected</u> by "a"

Real Neurons



How are signals affected by the passive properties of the membrane ?

Experiment 3



Local potentials are graded

resting potential

Almost no potential change is observed, why?

Current in axons and dendrites

Current pulse

Section of axon or dendrite of determined length (x). In this case <u>1 cm.</u>

ra axial resistance (Ω/cm) rm membrane resistance (Ω*cm)

m

Axial resistance increases with distance (x)

Tal Ta2 Ta3 Ta4

Total axial resistance

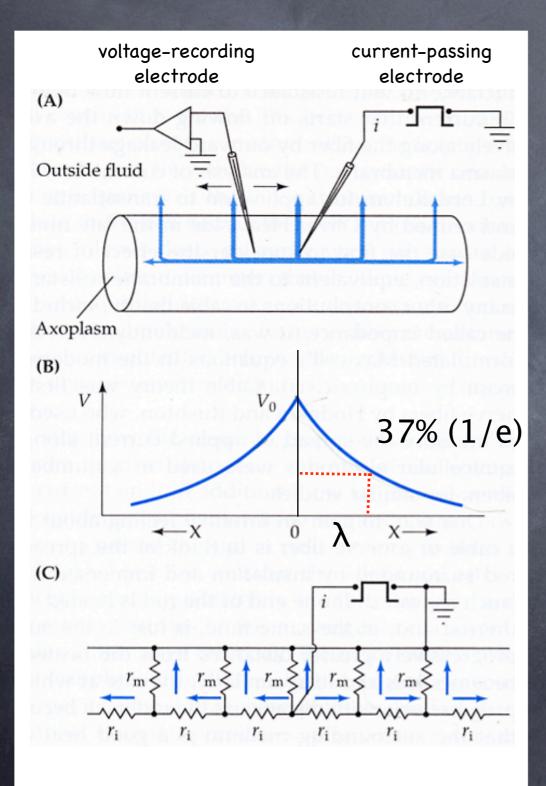
 $\Gamma X = \Gamma_a X (x = 4)$

(remember RT = R1 + R2)

Near the site of injection, the current flows V_0 through r_m (less resistance)

Then $V_0 = I_m * r_m$

What is the value of V at increasing distances from the site of current injection?



 $V = V_0 * e^{-\chi/\lambda}$

 λ is the length constant $\lambda = \sqrt{(\Gamma_m/\Gamma_a)}$ (cm) Increasing Γ_m increases λ Decreasing Γ_a increases λ <u>i.e. V is closer to Vo</u> For 1 cm of cytoplasm (dendrites or axon)

 ρ ($\Omega*cm$) resistive property of 1 cm³ of cytoplasm (dendrites or axon)

$$\mathbf{r}_a = \rho / (\pi a^2)$$

 $\mathbf{r}_{m} = \mathbf{R}_{m}/(2\pi a)$

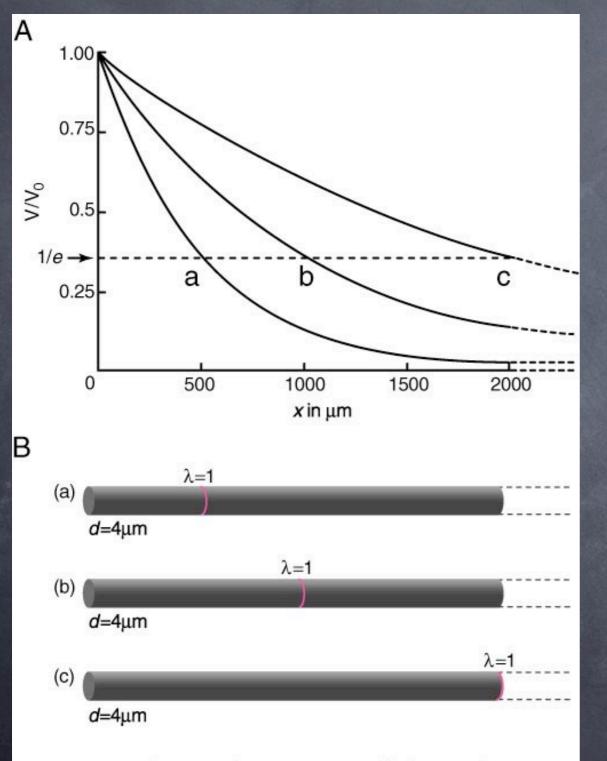
 $\begin{array}{l} \leftarrow 1 \text{ cm} \leftarrow \\ \lambda = \sqrt{(\Gamma_m/\Gamma_a)} & \lambda = \sqrt{\frac{R_m * a}{2\rho}} & \text{ If } R_m \text{ and } \rho \text{ are } \\ \end{array}$

$\lambda = \sqrt{K a}$

The length constant is proportional to the square root of the radius of the process

For neurons is usually 0.1 to 1 mm

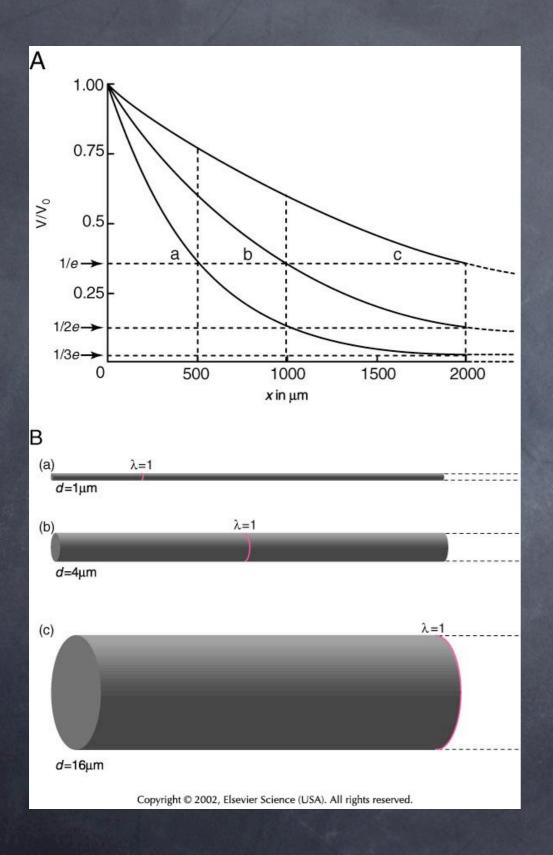
Effect of length constant



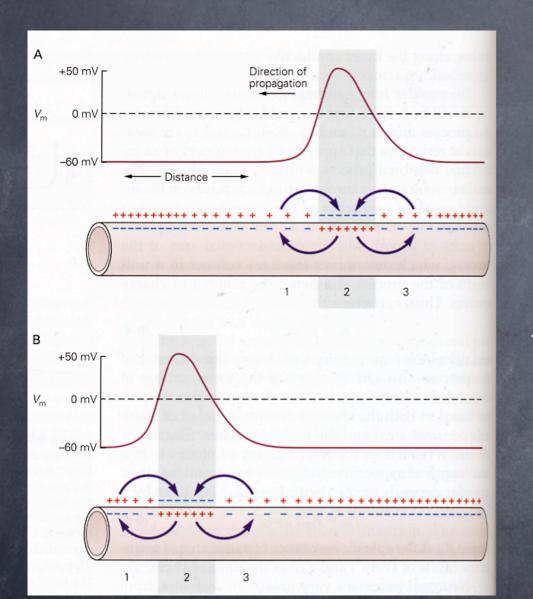
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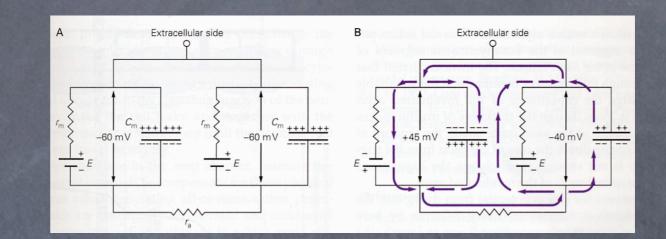
For a dendrite or axon with the same diameter as the <u>length constant</u> increases the potential <u>decreases less with</u> <u>distance</u>.

Effect of diameter



For a dendrite or axon with <u>increasing diameters</u> the <u>length constant</u> <u>increases</u> and the potential decreases less with distance. The passive properties of membranes and axon diameter affect the speed of conduction of action potentials



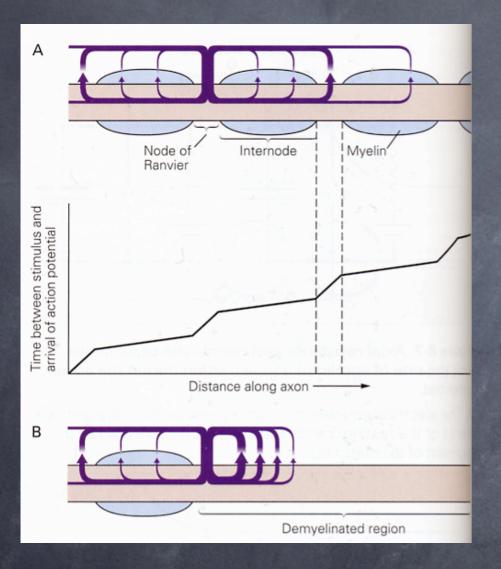


<u>speed of conduction of action potentials is</u> <u>inversely related to ra*cm</u>

speed of conduction is increased by increasing the diameter of the axon which decreases r_a

The giant axon of the squid 1 mm !

Myelination, the alternative to increasing the diameter of the axon.



Glial cell wrap around axons many times (20–160 times) this like adding 320 membranes (in series). This increases Rm and decreases Cm